

Title (en)
STRING WITH REDUCED WETTING FOR RIBBON CRYSTALS

Title (de)
FADEN MIT VERRINGERTER BENETZUNG FÜR BANDKRISTALLE

Title (fr)
FIL À MOUILLAGE RÉDUIT POUR DES CRISTAUX EN RUBAN

Publication
EP 2186139 B1 20120321 (EN)

Application
EP 08828340 A 20080829

Priority
• US 2008074715 W 20080829
• US 96926307 P 20070831

Abstract (en)
[origin: WO2009029741A1] A string for use in a string ribbon crystal has a base portion with a refractory material, and an externally exposed layer radially outward of the refractory material. The base portion has a coefficient of thermal expansion that is generally matched with the coefficient of thermal expansion for silicon. The externally exposed layer has a contact angle with silicon of between about 15 and 120 degrees.

IPC 8 full level
H01L 31/18 (2006.01); **C30B 15/34** (2006.01); **C30B 15/36** (2006.01); **C30B 35/00** (2006.01)

CPC (source: EP US)
C04B 35/62849 (2013.01 - EP US); **C04B 35/62852** (2013.01 - EP US); **C04B 35/62863** (2013.01 - EP US); **C04B 35/62868** (2013.01 - EP US); **C04B 35/62871** (2013.01 - EP US); **C04B 35/62873** (2013.01 - EP US); **C04B 35/62894** (2013.01 - EP US); **C30B 15/34** (2013.01 - EP US); **C30B 15/36** (2013.01 - EP US); **C30B 35/00** (2013.01 - EP US); **C04B 2235/5248** (2013.01 - EP US); **Y10T 117/1032** (2015.01 - EP US); **Y10T 428/24479** (2015.01 - EP US); **Y10T 428/24628** (2015.01 - EP US); **Y10T 428/2918** (2015.01 - EP US); **Y10T 428/2929** (2015.01 - EP US); **Y10T 428/2942** (2015.01 - EP US); **Y10T 428/2962** (2015.01 - EP US); **Y10T 428/30** (2015.01 - EP US)

Designated contracting state (EPC)
AT BE BG CH CY CZ DE DK EE ES FI FR GB GR HR HU IE IS IT LI LT LU LV MC MT NL NO PL PT RO SE SI SK TR

DOCDB simple family (publication)
WO 2009029741 A1 20090305; AT E550788 T1 20120415; CA 2697374 A1 20090305; CA 2697403 A1 20090305; CN 101784701 A 20100721; CN 101785116 A 20100721; CN 101821433 A 20100901; EP 2183411 A1 20100512; EP 2183411 B1 20130821; EP 2186139 A1 20100519; EP 2186139 B1 20120321; EP 2650406 A1 20131016; ES 2386999 T3 20120910; ES 2436293 T3 20131230; JP 2010537934 A 20101209; KR 20100049082 A 20100511; MX 2010002309 A 20100322; US 2009060823 A1 20090305; US 2009061163 A1 20090305; US 2009061224 A1 20090305; US 2010092776 A1 20100415; US 2011247546 A1 20111013; US 2013047914 A1 20130228; US 7651768 B2 20100126; US 7842270 B2 20101130; US 8309209 B2 20121113; WO 2009029752 A1 20090305; WO 2009029761 A1 20090305

DOCDB simple family (application)
US 2008074715 W 20080829; AT 08828340 T 20080829; CA 2697374 A 20080829; CA 2697403 A 20080829; CN 200880103858 A 20080829; CN 200880103885 A 20080829; CN 200880103887 A 20080829; EP 08798930 A 20080829; EP 08828340 A 20080829; EP 13175698 A 20080829; ES 08798930 T 20080829; ES 08828340 T 20080829; JP 2010523151 A 20080829; KR 20107003806 A 20080829; MX 2010002309 A 20080829; US 2008074731 W 20080829; US 2008074741 W 20080829; US 20099608 A 20080829; US 201113079838 A 20110405; US 20111708 A 20080829; US 20118008 A 20080829; US 201213654070 A 20121017; US 63395109 A 20091209